

**Product data sheet** 

## 1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in a leadless medium power DFN2020MD-6 (SOT1220) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

## 2. Features and benefits

- Extended temperature range T<sub>i</sub> = 175 °C
- Side wettable flanks for optical solder inspection
- Small and leadless ultra thin SMD plastic package: 2 x 2 x 0.65 mm
- Trench MOSFET technology
- AEC-Q101 qualified

## 3. Applications

- Relay driver
- High-speed line driver
- High-side load switch
- Switching circuits

## 4. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	-60	V
V <sub>GS</sub>	gate-source voltage	-		-20	-	20	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = -10 V; T <sub>sp</sub> = 25 °C		-	-	-8	А
P <sub>tot</sub>	total power dissipation	T <sub>sp</sub> = 25 °C		-	-	15	W
Static chara	acteristics	- -	·				,
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = -10 V; I <sub>D</sub> = -3 A; T <sub>j</sub> = 25 °C		-	95	120	mΩ

# nexperia

60 V, P-channel Trench MOSFET

# 5. Pinning information

Table	2.	Pinning	information
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Pin	Symbol	Description	Simplified outline	Graphic symbol
1	D	drain		D
2	D	drain		
3	G	gate		G-UF
4	S	source		S
5	D	drain	Transparent top view	017aaa094
6	D	drain	DFN2020MD-6 (SOT1220)	
7	D	drain		
8	S	source		

# 6. Ordering information

## Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
BUK6D120-60P	DFN2020MD-6	DFN2020MD-6: plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals	SOT1220		

# 7. Marking

#### Table 4. Marking codes

Type number	Marking code
BUK6D120-60P	4S

# 8. Limiting values

### Table 5. Limiting values

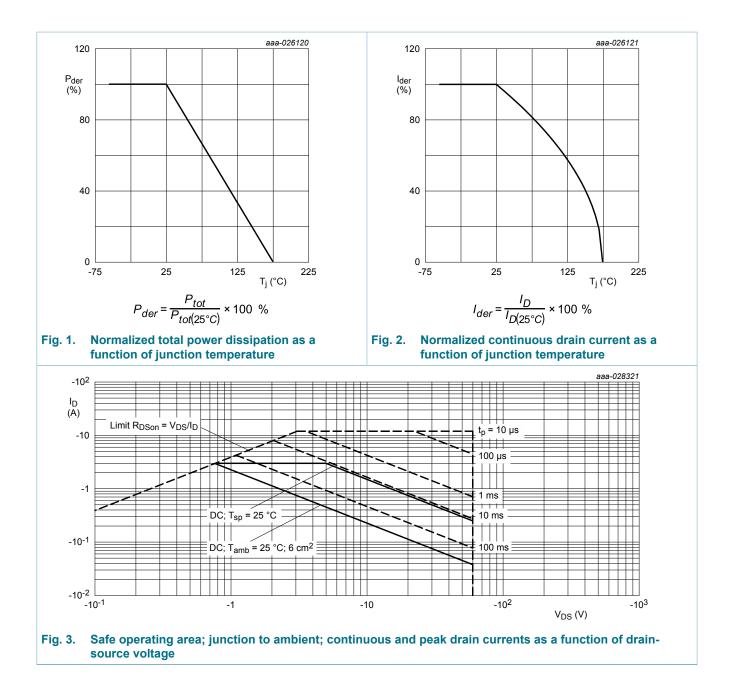
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-60	V
V <sub>GS</sub>	gate-source voltage			-20	20	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = -10 V; T <sub>sp</sub> = 25 °C		-	-8	А
		V <sub>GS</sub> = -10 V; T <sub>sp</sub> = 100 °C		-	-5.1	А
		V <sub>GS</sub> = -10 V; T <sub>amb</sub> = 25 °C	[1]	-	-3	А
I <sub>DM</sub>	peak drain current	$T_{sp}$ = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	-32	А
P <sub>tot</sub>	total power dissipation	T <sub>sp</sub> = 25 °C		-	15	W
		T <sub>amb</sub> = 25 °C	[1]	-	2.3	W
Tj	junction temperature			-55	175	°C
T <sub>amb</sub>	ambient temperature			-55	175	°C
T <sub>stg</sub>	storage temperature			-65	175	°C
Source-drai	n diode		·	·		
I <sub>S</sub>	source current	T <sub>sp</sub> = 25 °C		-	-8	А
		T <sub>amb</sub> = 25 °C	[1]	-	-2.3	А
I <sub>SM</sub>	peak source current	single pulse; $t_p \le 10 \ \mu s$ ; $T_{sp} = 25 \ ^{\circ}C$		-	-32	А
ESD maxim	um rating		·	·		
V <sub>ESD</sub>	electrostatic discharge voltage	НВМ	[2]	-	500	V
Avalanche r	uggedness					
E <sub>DS(AL)S</sub>	non-repetitive drain- source avalanche energy	$T_{j(init)}$ = 25 °C; $I_D$ = -0.85 A; DUT in avalanche (unclamped)		-	28	mJ
					1	

Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6  $\rm cm^2.$  Measured between all pins. [1] [2]

# BUK6D120-60P

#### 60 V, P-channel Trench MOSFET

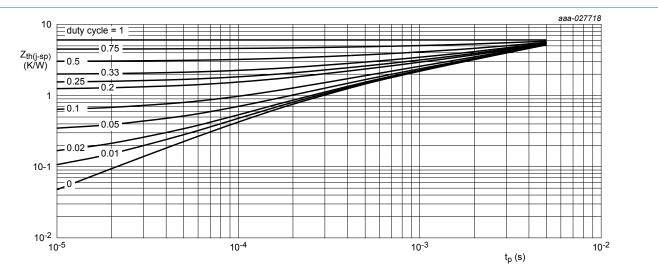


## 9. Thermal characteristics

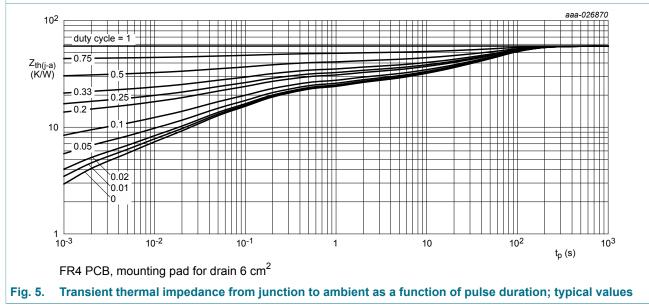
Table 0. Therma	al characteristics						
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	[1]	-	57	66	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	6	10	K/W

## Table 6 Thormal characteristics

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.







# **10. Characteristics**

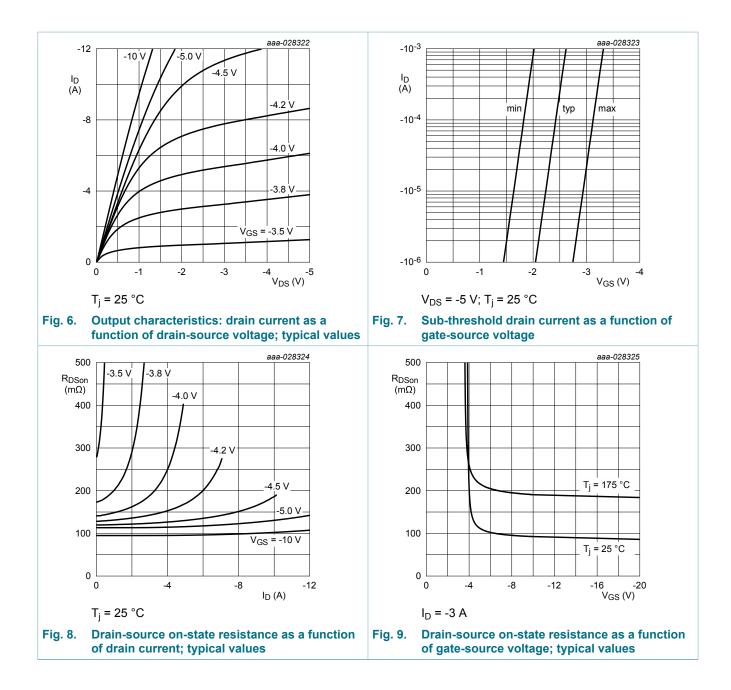
#### **Table 7. Characteristics**

 $T_i$  = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics		1			
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	I <sub>D</sub> = -250 μA; V <sub>GS</sub> = 0 V	-60	-	-	V
V <sub>GSth</sub>	gate-source threshold voltage	$I_D$ = -250 µA; $V_{DS}$ = $V_{GS}$ ; $T_j$ = 25 °C	-1.9	-2.5	-3.2	V
I <sub>DSS</sub>	drain leakage current	$V_{DS}$ = -60 V; $V_{GS}$ = 0 V; $T_j$ = 25 °C	-	-	-1	μA
		$V_{DS}$ = -60 V; $V_{GS}$ = 0 V; $T_j$ = 175 °C	-	-	-500	μA
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = -20 V; V <sub>DS</sub> = 0 V	-	-	-100	nA
		V <sub>GS</sub> = 20 V; V <sub>DS</sub> = 0 V	-	-	100	nA
R <sub>DSon</sub>	drain-source on-state	V <sub>GS</sub> = -10 V; I <sub>D</sub> = -3 A; T <sub>j</sub> = 25 °C	-	95	120	mΩ
	resistance	V <sub>GS</sub> = -10 V; I <sub>D</sub> = -3 A; T <sub>j</sub> = 175 °C	-	202	256	mΩ
		$V_{GS}$ = -4.5 V; I <sub>D</sub> = -2.5 A	-	125	170	mΩ
9 <sub>fs</sub>	forward transconductance	V <sub>DS</sub> = -10 V; I <sub>D</sub> = -3 A	-	13	-	S
R <sub>G</sub>	gate resistance	f = 1 MHz	-	8	-	Ω
Dynamic ch	naracteristics		·			
Q <sub>G(tot)</sub>	total gate charge	$V_{DS}$ = -30 V; I <sub>D</sub> = -3 A; V <sub>GS</sub> = -10 V	-	12	18	nC
Q <sub>GS</sub>	gate-source charge	V <sub>DS</sub> = -30 V; I <sub>D</sub> = -3 A; V <sub>GS</sub> = -10 V	-	2.6	-	nC
Q <sub>GD</sub>	gate-drain charge		-	2.6	-	nC
C <sub>iss</sub>	input capacitance	$V_{DS}$ = -30 V; f = 1 MHz; $V_{GS}$ = 0 V	-	724	-	pF
C <sub>oss</sub>	output capacitance		-	55	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	30	-	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS}$ = -30 V; I <sub>D</sub> = -3 A; V <sub>GS</sub> = -10 V;	-	9	-	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 6 \Omega$	-	10	-	ns
t <sub>d(off)</sub>	turn-off delay time		-	24	-	ns
t <sub>f</sub>	fall time	]	-	18	-	ns
Source-drai	in diode					
V <sub>SD</sub>	source-drain voltage	$I_{\rm S}$ = -2.3 A; $V_{\rm GS}$ = 0 V	-	-0.8	-1.2	V
t <sub>rr</sub>	reverse recovery time	$I_{S} = -2.3 \text{ A}; \text{ dI}_{S}/\text{dt} = 100 \text{ A}/\mu\text{s};$	-	24	-	ns
Q <sub>r</sub>	recovered charge	V <sub>GS</sub> = 0 V; V <sub>DS</sub> = -30 V; T <sub>j</sub> = 25 °C	-	24	-	nC

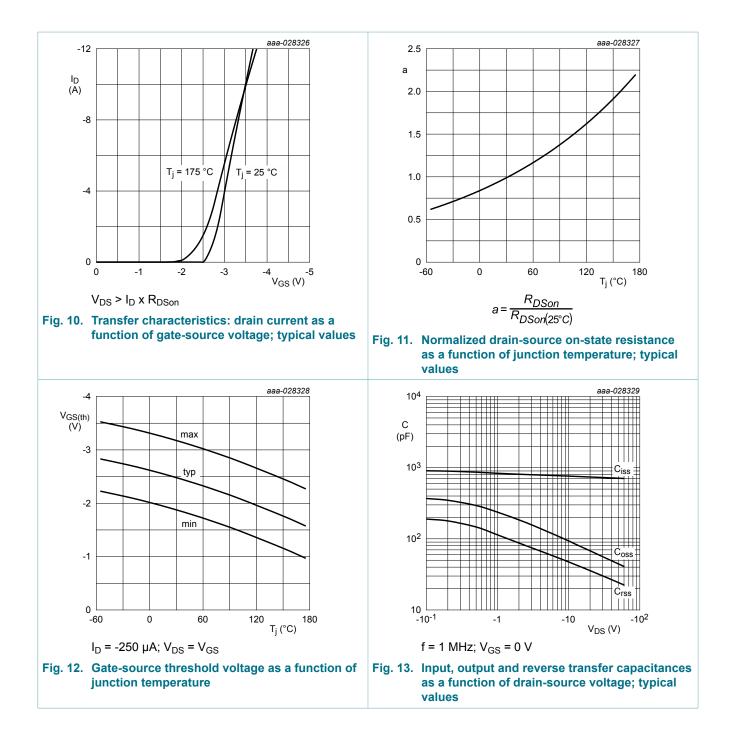
# BUK6D120-60P

#### 60 V, P-channel Trench MOSFET



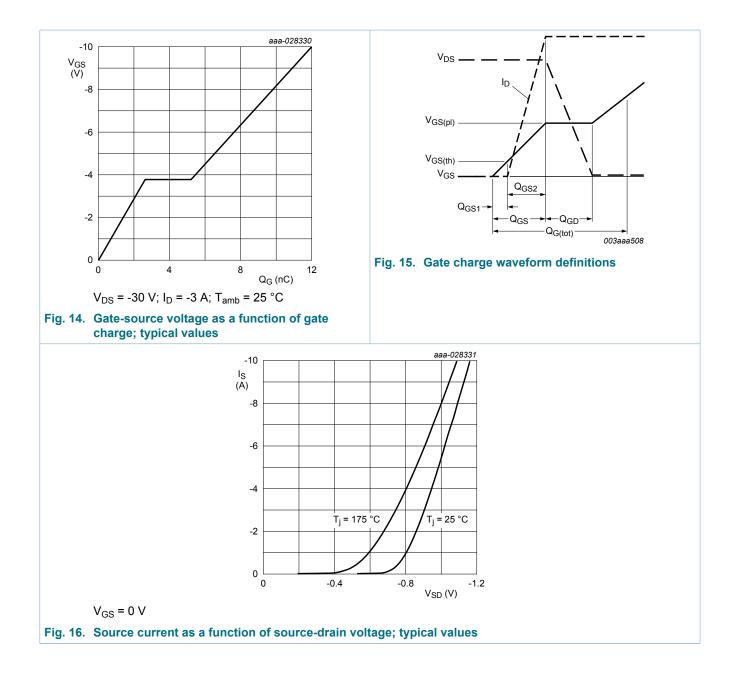
# BUK6D120-60P

#### 60 V, P-channel Trench MOSFET

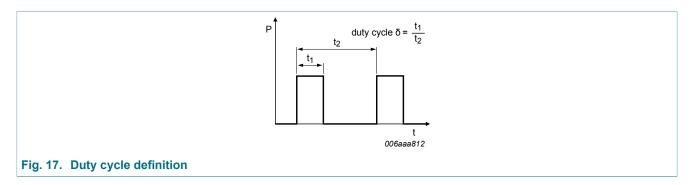


# BUK6D120-60P

#### 60 V, P-channel Trench MOSFET



# 11. Test information

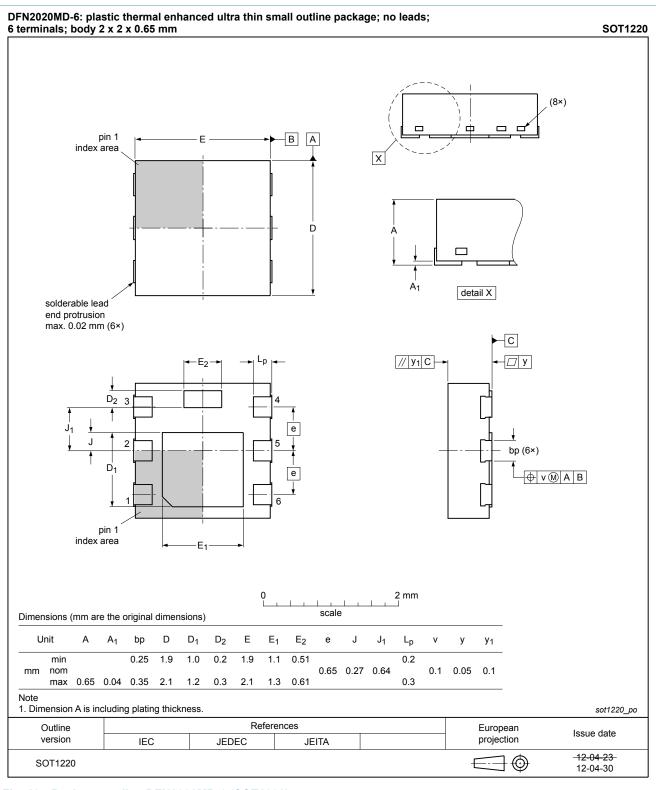


## **Quality information**

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

60 V, P-channel Trench MOSFET

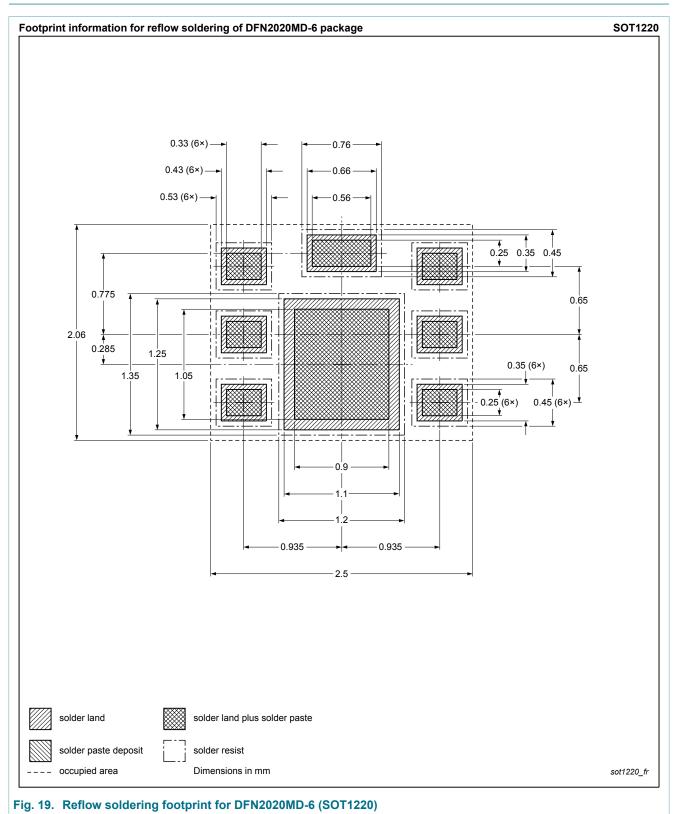
## 12. Package outline



### Fig. 18. Package outline DFN2020MD-6 (SOT1220)

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## 13. Soldering



# 14. Revision history

Table 8. Revision history						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
BUK6D120-60P v.1	20180403	Product data sheet	-	-		

#### 60 V, P-channel Trench MOSFET

# 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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